UNIT I

Introduction to Electronics

1. The process by which impurities are added to	a. 5 eV
a pure semiconductor is	b. 10 eV
a. Diffusing	c. 15 eV
b. Drift	d. 1 eV
c. Doping	
d. Mixing	Ans: d
Ans: c	6.A semiconductor diode has forward resistance of the order of
2. When an atom gains or losses an ion it is said	а. Ω
to be	b. KΩ
a. lonised	c. MΩ
b. Bonded	d. none of the above
c. Excited	
d. stabilized	Ans: a
Ans: a	7. The reverse current in a diode is of the order
	of
3. Barrier potential for silicon diode	а. μА
a. 0.3	b. mA
b. 0.4	c. A
c. 0.7	d. KA
d. 0.1	
	Ans: a
Ans: c	
	8.A reverse-biased diode acts like
4. The manufacturer of diode provides the detail	a. open switch
information about diode, in the form of	b. closed switch
a. excel sheet	c. small resistance
b. Data Sheet	d. none of the above
c. Log sheet	
d. None of above	Ans: a
Ans: b	9. The potential barrier at a PN-junction is due to
	the charges on either side of the junction. These
5. In a semiconductor, the energy gap between	charges are
valence band and conduction band is about	a. minority carriers
	b. majority carriers
	c. both majority and minority carriers

d. fixed donor and acceptor ions

Ans: d

10. When we apply reverse bias to a junction diode, it

a. lowers the potential barrier

b. raises the potential barrier

c. greatly increases the minority-carrier current

d. greatly increases the majority-carrier current

Ans: b

11. The turn-on voltage of a Ge junction diode is nearly..... volts.

a. 0.7

b. 0.3

c. 1

d. 0.1

Ans: b

12. If a pure silicon crystal has one million free electrons inside it, how many holes does it have?

a. One million

- b. two million
- c. zero
- d. ten million

Ans: a

13.A strong electric field across a P-N junction that causes covalent bond to break apart is called

a. avalanche breakdown

- b. reverse breakdown
- c. Zener Breakdown
- d. Low voltage break down

Ans: c

- 14. Resistivity of semiconductor depends on...
- a. shape of the semiconductor
- b. atomic nature of semiconductor
- c. width of semiconductor
- d. length of semiconductor

Ans : b

15. At room temperature, the current in the intrinsic semiconductor is due to....

- a. Holes
- b. electrons
- c. lons
- d. holes and electrons

Ans : d

16. If the temperature of an extrinsic semiconductor is increased so that the intrinsic carrier concentration is doubled, then

- a. The majority carrier density doubles
- b. the minority carrier density is doubled

c. the minority carrier density becomes 4 times the original value

d. both majority and minority carrier densities double

Ans : c

17. When holes leave the p-material to fill electrons in the n-material the process is called

- a. Mixing
- b. Depletion
- c. Diffusion
- d. Depletion

Ans : c

- 18. Diffusion current in the diode is caused by
- a. Chemical energy
- b. heat energy
- c. voltage

d. crystal formation

Ans : a

19. Depletion region in a pn diode is due toa. reverse biasingb. forward biasingc. an area created by crystal dopingd. an area void of current carriers

Ans: a

20. When a diode is forward biaseda. Barrier potential increasesb. Barrier potential decreasesc. Majority current reducesd. Minority current reduces

Ans: b

21. The p-n junction forms device calleda. Triacb. Diodec. multiplexer .d. Semiconductor

Ans: b

22. The normal forward biased operation of diode isa. Below the knee pointb. at the originc. above knee pointd. all the above

Ans: c

23. In diode reverse current is due toa. Mobile donor ionsb. Mobile acceptor ionsc. minority carriersd. majority carriers

Ans: c

- a. 1st Quadrant
- b. 2nd Quadrant
- c. 3rd Quadrant
- d. 4th Quadrant

Ans: c

25. In an unbiased PN-junction, the junction current at equilibrium is
a. due to diffusion of minority carriers only
b. due to diffusion of majority carriers only
c. zero, because equal but opposite carriers are crossing the junction
d. zero, because no charges are crossing the junction

Ans: c

26. In a PN-junction diode, holes diffuse from the P region to the N region becausea. the free electrons in the N region attract themb. they are swept across the junction by the potential differencec. there is greater concentration of holes in the P region as compared to N region

d. none of the above

Ans: c

27. The number of minority carriers crossing the junction of a diode depends primarily on thea. concentration of doping impuritiesb. magnitude of the potential barrierc. magnitude of the forward-bias voltaged. rate of thermal generation of electron –holepairs

Ans: d

28. The forward bias applied to a PN- junction diode is increased from zero to higher values. Rapid increase in the current flow for a relatively small increase in voltage occurs

a. immediately

b. only after the forward bias exceeds the potential barrier

c. when the flow of minority carriers is sufficient to cause an avalanche breakdown

d. when the depletion area becomes larger than the space-charge area

Ans: b

29. If the arrow of a semiconductor diode symbol is positive w.r.t. bar, then diode is....biased.

a. reverse

b. forward

- c. none of the two
- d. forward or reverse

Ans: b

30. The leakage current in a semiconductor diode is due to......a. minority carriersb. majority carriersc. junction capacitanced. none of the above

Ans: a

31. The ideal value of reverse resistance of diode is

- a. high
- b. infinite
- c. zero

d. very low

Ans: b

32. The ideal value of forward resistance of diode is

a. high
b. infinite
c. zero
d. very low

Ans: c

33. Rectifier converts

a. a.c. voltage to d.c.voltage
b. a.c voltage to pulsating d.c voltage
c. d.c voltage to a.c. voltage
d. a.c voltage to a.c. voltage

Ans: b

34. Efficiency of half wave rectifier is

a. 81.20%

- b. 40.60%
- c. 45.6 %
- d. 82.10%

Ans: b

35. No. of diodes used in full wave rectifier is

- a. 1
- b. 2

c. 3 d. 4

Ans: b

36. In a full-wave rectifier, the current in each of the diodes flows fora. the complete cycle of the input signalb. half cycle of the input signalc. less than half cycle of the input signal

d. zero time

Ans: b

37. The peak value of the input to a half wave rectifier is 10V. the approximate peak value of the output is

a. 10 V

b. 3.18V

c. 10.7V

d. 9.3V

Ans: d

38. The total secondary voltage in a centre tapped full wave rectifier is 125 V rms. Neglecting the diode drop, the rms output voltage is

a. 125V

b. 177V c. 100V

d. 62.5V

Ans: d

39. a half-wave rectifier, the peak value of the ac voltage across the secondary of the transformer is 20V2 V. If no filter circuit is used, the maximum dc voltage across the load will be

a. 28.28 V b. 14.14 V

c. 20 V

d. 9 V

Ans: d

40. What is the frequency of the capacitor ripple voltage in a full-wave rectifier circuit if the frequency of the transformer secondary voltage is 60 Hz?

a. 60Hz

b. 50Hz

c. 120Hz

d. this is impossible to determine

Ans: c

41. What is the dc output voltage of an unfiltered half-wave rectifier whose peak output voltage is 9.8 V?

a. 6.23 V b. 19.6 V

c. 9.8 V

d. 3.1 V

Ans: d

42. If Vm is the peak voltage across the secondary of the transformer in a half-wave rectifier(without any filter circuit. , then the maximum voltage on the reverse biased diode is

- a. Vm
- b. ½. Vm

c. 2 Vm

d. none of the above

Ans: a

43. If you are checking a 60 Hz full wave bridge rectifier and observe that the output has 60Hz ripple

- a. the circuit is working properly
- b. there is an open diode
- c. the transformer secondary is shorted
- d. the filter capacitor is leaky

Ans: b

42. Efficiency of half wave rectifier is
a. 81.20%
b. 40.60%
c. 45.60%
d. 82.1 %
Ans: b
43. Ripple factor of full wave rectifier is

a. 0.122

b. 0.4	c. 9.8 v
c. 0.48	d. 3.1
d. 0.05	

Ans: c

44. Efficiency of bridge rectifier is a. 81.2 % b. 40.6 % c. 45.60% d. 82.1 %

Ans: a

45. In an unbiased PN-junction, the junction current at equilibrium is

a. due to diffusion of minority carriers only

b. due to diffusion of majority carriers only

c. zero, because equal but opposite carriers are crossing the junction

d. zero, because no charges are crossing the junction

Ans: c

46. If Vm is the peak voltage across the secondary of the transformer in a full-wave rectifier with a shunt capacitor filter circuit, then the maximum voltage on the reverse biased diode is

a. Vm

b. ½. Vm

c. 2 Vm

d. both A and B

Ans: c

47. What is the dc output voltage of an unfiltered half-wave rectifier whose peak output voltage is 9.8V?

a. 6.23 V

b. 19.6 V

V V

Ans: d

48. What is the frequency of the capacitor ripple voltage in a full-wave rectifier circuit if the frequency of the transformer secondary voltage is 60 Hz?

a. 60Hz

b. 50 Hz

c. 120 Hz

d. this is impossible to determine

Ans: c

49. The output from an unfiltered half-wave or full wave rectifier is --

- a. a pulsating dc
- b. steady dc voltage
- c. smooth dc voltage
- d. none of the above

Ans: a

50. What is the approximate dc output voltage from a filtered bridge rectifier whose peak output voltage is 30V?

a. 19.1 V b. 9.5 V c. 30 V d. none of the above

Ans: c

51.A half wave rectified sinusoidal waveform has a peak voltage of 12V. Its average value and rms value of the fundamental components are; respectively given by a. 15/p V, 7.5 V

b. 20/p V, 10/Ö2 V c. 12/p V, 6 V

d. none of these

Ans: c

52. In a bridge rectifier circuit we use

a. no centre-tapping and diode having peak inverse voltage Vm

b. no centre tapping and diode having inverse voltage 2Vm

c. centre tapping and diode having reverse voltage Vm

d. centre- tapping and diode having reverse voltage 2Vm

Ans: a

53.A device converting a.c. to d.c. is called

- a. comparator
- b. inverter
- c. rectifier
- d. regulator

Ans: c

- 53. PIV rating of diode in a bridge rectifier is
- a. Vm
- b. 2Vm
- c. Vm/2
- d. none of these

Ans: a

54. In HWR the peak value of ac voltage across secondary of transformer is 20V2 V if no filter circuit is used, the maximum d.c. voltage across the load will be

- a. 28.28 V
- b. 14.14 V
- c. 20 V
- d. 9 V

Ans: d

55. If Vm is the peak voltage across secondary of transformer in HWR (without any filter circuit. , then the maximum voltage on reverse biased diode is

- a. Vm
- b. 1/2Vm
- c. 2Vm
- d. none of the above

Ans: a

56. If Vm is the peak voltage across secondary of transformer in HWR , if we use shunt capacitor filter, the maximum voltage that occurs on reverse biased diode is

- a. Vm
- b. 1/2Vm
- c. 2Vm
- d. none of the above

Ans: a

57. In Center tap FWR Vm is the peak voltage between center tap and one end of secondary, the maximum voltage that occurs on reverse biased diode is

- a. Vm
- b. 1/2Vm
- c. 2Vm
- d. none of the above

Ans: c

58. In HWR the load current flows for

- a. the complete cycle of input signal.
- b. only for positive half cycle of input signal.
- c. less than half cycle of input signal.
- d. more than half cycle but lass than complete cycle of input signal.

Ans: b

59. What is the dc output voltage of an unfiltered half-wave rectifier whose peak output voltage is 9.8 V?

- a. 6.23 V
- b. 19.6 V
- c. 9.8 V
- d. 3.1 V
- Ans : d

60. What is the frequency of the capacitor ripple voltage in a full-wave rectifier circuit if the frequency of the transformer secondary voltage is 60 Hz?

a. 60Hz

- b. 50 Hz
- c. 20 Hz
- d. this is impossible to determine

Ans: c

61. In a full-wave rectifier, the dc load current equals 1A. How much dc current is carried by each diode?

- a. ½ A
- b. 1 A
- c. 2 A
- d. 0 A

Ans: a

62.A half wave rectified sinusoidal waveform has a peak voltage of 12V. Its average value and rms value of the fundamental components are; respectively given by

a. 15/p V, 7.5 V b. 20/p V, 10/Ö2 V c. 12/p V, 6 V d. none of these 63. In a bridge rectifier circuit we use

a. no centre-tapping and diode having peak inverse voltage Vm

b. no centre tapping and diode having inverse voltage 2Vm

c. centre tapping and diode having reverse voltage Vm

d. centre- tapping and diode having reverse voltage 2Vm

Ans : a

64. In a full wave rectifier with R-C filter, the conduction angle 12 of the diode is

- a. O
- b. less than 180
- c. Equal to 180
- d. More than 0

Ans: b

65. The average value of a half wave rectified voltage with a peak value of 200V is
a. 63.7V
b. 127.3 V
c. 141V
d. 0V

Ans : a

66. When a 60 Hz sinusoidal voltage is applied to the input of a half wave rectifier, the output frequency is

- a. 120 Hz
- b. 30 Hz
- c. 60 Hz
- d. 0 Hz

Ans : c

Ans: c

67. The peak value of the input to a half wave rectifier is 10V. the approximate peak value of the output is

a. 10 V

b. 3.18 V c. 10.7 V

d. 9.3 V

Ans :d

68. The average value of full wave rectified voltage with a peak value of 75V is

a. 53 V

b. 47.8 V

c. 37.5 V

d. 23.9 V

Ans :b

9.When a 60Hz sinusoidal voltage is applied to the input of a full wave rectifier, the output frequency is

a. 120 Hz

- b. 60 Hz
- c. 240 Hz
- d. 0 V

Ans : a

70. The total secondary voltage in a centre tapped full wave rectifier is 125 V rms. Neglecting the diode drop, the rms output voltage is

a. 125V

- b. 177 V
- c. 100 V
- d. 62.5 V

Ans : d

71. When the peak output voltage is 100V, the PIV for each diode in a centre- tapped full wave rectifier is(neglecting the diode drop.

a. 100 V

- b. 200 V
- c. 141 V
- d. 50V

Ans : b

72. When the rms output voltage of a bridge fullwave rectifier is 20V, the peak –inverse voltage across the diodes is (neglecting the diode drop.

- a. 20 V
- b. 40 V c. 28.3 V
- d. 56.6 V

Ans : c

73.A 60 V peak full wave rectified voltage is applied to a capacitor input filter. If f=120 Hz, RL =10K and C= 10 μ F, the ripple voltage is a. 0.6 V b. 6 mV

- c. 5 V
- d. 2.88 V

Ans : d

74. If one of the diodes in a bridge full wave rectifier opens, the output isa. 0Vb. one-fourth the amplitude of the input voltage

- c. a half wave rectified voltage
- d. a 120Hz voltage

Ans : c

75. If you are checking a 60 Hz full wave bridge rectifier and observe that the output has 60Hz ripple

- a. the circuit is working properly
- b. there is an open diode
- c. the transformer secondary is shorted
- d. the filter capacitor is leaky

Ans : b

76. With a half wave rectified voltage across the load resistor, load current flows for what part of a cycle?

- a. 0 degree
- b. 90 degree
- c. 180 degree
- d. 360 degree

Ans : c

77. Suppose line voltage may be as low as 105 V rms or as high as 125 V rms in a half wave rectifier. With a 5 : 1 step down transformer, the minimum peak load voltage is closest to

- a. 21 V
- b. 25 V
- c. 29.7 V
- d. 35.4 V

Ans : c

- 78. The voltage out of a bridge rectifier is a
- a. half wave signal
- b. full wave signal
- c. bridge rectified signal
- d. sine wave
- Ans : b

79. What is the peak load voltage in a full wave rectifier if the secondary voltage is 20 V rms?

- a. 0 V
- b. 0.7 V

c. 14.1 V d. 28.3 V

u. 20.5 v

Ans : c

80. We want a peak load voltage of 40 V out of a bridge rectifier. What is the approximate rms value of secondary voltage?

- a. 0 V
- b. 14.4 V
- c. 28.3 V
- d. 56.6 V

Ans : c

81. With a full wave rectified voltage across a load resistor, load current flows for what part of a cycle?

- a. O degree
- b. 90 degree
- c. 180 degree
- d. 360 degree

Ans : d

82. With the same secondary voltage and filter, which of the following has the most ripple?

- a. half wave rectifier
- b. full wave rectifier
- c. bridge rectifier
- d. impossible to say

Ans : a

83. With the same secondary voltage and filter which of the following produces the least load voltage?

- a. half wave rectifier
- b. full wave rectifier
- c. bridge rectifier
- d. impossible to say

Ans : a

	Ans : a
84. If the filtered load current is 10 mA, which of	
the following has a diode current of 10 mA?	89. Ripple factor of full wave rectifier is
a. half wave rectifier	a. 0.122
b. full wave rectifier	b. 0.4
c. bridge rectifier	c. 0.48
d. All above	d. 0.05
Ans : d	Ans : c
85. The diodes in a bridge rectifier each have a	90. Efficiency of bridge rectifier is
maximum dc current rating of 2 A. this means the	a. 81.2 %
dc load current can have maximum value of	b. 40.6 %
a. 1 A	c. 45.6 %
b. 2 A	d. 82.1 %
c. 4 A	
d. 8 A	Ans : a
Ans : b	91. Ripple factor of bridge rectifier is
	a. 0.122
86. Efficiency of half wave rectifier is	b. 0.4
a. 81.2 %	c. 0.48
b. 40.6 %	d. 0.05
c. 45.6 %	
d. 82.1 %	Ans : c
Ans : b	92. In a full-wave rectifier, the current in each of
	the diodes flows for
87. Ripple factor of half wave rectifier is	a. the complete cycle of the input signal
a. 2.122	 b. half cycle of the input signal
b. 1.112	c. less than half cycle of the input signal
c. 1.211	d. zero time
d. 2.11	
	Ans : b
Ans : c	
	93. To minimize the ripple content in the circuit
88. Efficiency of full wave rectifier is	a. Diode circuit is used
a. 81.2 %	b. filter circuit is used
b. 40.6 %	c. bridge circuit is used
c. 45.6 %	d. none of the above
d. 82.1 %	

Ans: b

94. What is the frequency of the capacitor ripple voltage in a full-wave rectifier circuit if the frequency of the transformer secondary voltage is 60 Hz?

- a. 60Hz
- b. 50Hz
- c. 120Hz
- d. this is impossible to determine

Ans: c

95. The ideal dc output voltage of a capacitor input filter is equal to

- a. the peak value of the rectified voltage
- b. the average value of the rectified voltage
- c. the rms value of the rectified voltage
- d. none of the above

Ans: a

96.A certain power supply filter produces an output with a ripple of 100 mV peak-to-peak and dc value of 20V. the ripple factor is

a. 0.05

- b. 0.005
- c. 0.0005
- d. 0.02

Ans: b

97. Line regulation is determined by

- a. load current
- b. zener current and load current
- c. changes in load resistance and output voltage
- d. changes in output voltage and input voltage

Ans: d

98. Load regulation is determined by a. changes in load current and input voltage

b. changes in load current and output voltage

c. changes in load resistance and input voltaged. changes in zener current and load current

Ans: d

99. If you are checking a 60 Hz full wave bridge rectifier and observe that the output has 60Hz ripple

- a. the circuit is working properly
- b. there is an open diode
- c. the transformer secondary is shorted
- d. the filter capacitor is leaky

Ans: b

100. Types of filter area. Capacitor input filterb. choke input filterc. resister input filterd. both A and B

Ans: d

101. Due to large., capacitor holds its entire charge.a. charging current

- b. time constant
- c. discharging current
- d. none of these

Ans: b

102. Due to thetime constant the capacitor holds its entire charge.a. zero

- b. negative
- c. very large
- d. unity

Ans: c

a. decreases 103. For a HWR using RL=1500 Ω , a capacitor filter is used with C=100µF then its ripple factor b. increases c. remains constant at 50HZ is..... d. none of these a. 0.115 b. 0.577 Ans: a c. 0.0288 d. 0.0385 108. As the value of filter capacitor decreases, the ripple factor of capacitor filter...... Ans: d a. decreases b. increases 104. For a FWR using RL=1000 Ω , a capacitor c. both a and b filter is used with C=100µF then its ripple factor d. None of the above at 50HZ is..... a. 0.115 Ans: b b. 0.577 c. 0.0288 109. As the value of filter capacitor increases, d. 0.0385 the ripple factor of capacitor filter...... a. decreases Ans: c b. increases c. both a and b 105. In a HWR using capacitor filter of 50µF, d. None of the above Esm=42V and Idc=2 mA then its output d.c. voltage is V. Ans: a a. 41.6 b. 42 110. As load resistance decreases, the ripple c. 41.8 factor of capcitor filter..... d. 55 a. decreases b. increases Ans: a c. remains constant d. none of these 106. In a FWR using capacitor filter of 50µF, Esm=42V and Idc=2 mA then its output d.c. Ans: b voltage is V. a. 41.6 As the value of filter capacitor 111. b. 42 increases..... c. 41.8 a. ripple factor increases d. 55 b. initial surge current increases c. regulation increases Ans: c d. all of these 107. As load resistance increases, the ripple Ans:b factor of capcitor filter.....

111. A capacitor of 470μ F is used as filter for a FWR using maximum input voltage of 30V at 50 HZ. Then its output d.c. voltage is.....V if RL=100 Ω .

a. 35.55

b. 25.94

c. 27.96

d. 39.54

Ans: c

112. A capacitor of 470μ F is used as filter for a HWR using maximum input voltage of 30V at 50 HZ. Then its output d.c. voltage is.....V if RL=100 Ω .

a. 35.55

b. 25.94

c. 27.96

d. 39.54

Ans: b

113. A capacitor of 100μ F is used as a filter for HWR supplying a load of RL= 1000Ω then ripple factor is.....

a. 0.002

b. 0.048

c. 0.0355

d. 0.0577

Ans: d

114. A capacitor of $470\mu F$ is used as a filter for bridge rectifier supplying a load of RL=1000 Ω then ripple factor is.....

a. 0.0288

b. 0.00614

c. 0.00355

d. 0.00577

Ans: b

115. The output d.c. voltage of a rectifier using a capacitor filter is 20V while its ripple factor is
2.88% then the r.m.s. value of ripple voltage is ..
a. 0.288
b. 0.576
c. 0.347
d. 0.144

Ans: b

116. If the rms value of ripple voltage is 0.2886V then peak to peak value of the ripple voltage is.....V assuming triangular nature of the ripple voltage. a. 0.204

- b. 0.408
- c. 0.5

d. 1

Ans: b

117. In a filter circuit.....is always connected in series with the load.a. resistorb. inductorc. capacitord. none of these

Ans: b

118. Ripple factoras the value of filter capacitor increases.
a. remains same
b. decreases
c. increases
d. none of these

Ans: b

d. none of these 119. The ripple factor for the capacitor filter isfor FWR. Ans: c a. 1/4√3fCRL b. 1/2fCRL 124. For FWR with capacitor filter, diode c. $1/2\pi fCRL$ conducts for half cycle. d. $1/\pi fCRL$ a. less than b. more than Ans: a c. equal to d. none of these 120. The ripple factor for the capacitor filter isfor HWR. Ans: a a. 1/4√3fCRL b. 1/2fCRL 125. The circuits used to remove unwanted c. 1/2πfCRL portion of waveform without disturbing the d. 1/2√3fCRL remaining part are called..... a. clampers Ans: d b. clippers c. chopper 121. The ripple factor for the capacitor filter is d. integratorfor Bridge FWR rectifier. a. 1/4√3fCRL Ans: b b. 1/2fCRL c. $1/2\pi fCRL$ 126. The clipper circuits are also called as d. 1/2√3fCRL a. filters b. rectifiers Ans: a c. limiters d. integrators 122. If looking from the rectifier side, the first element in the filter is a capacitor then it is called Ans: c filter. a. Choke input 127. In a clamper, is necessary in addition b. capacitor to a diode. ς. π a. transistor d. RC b. inductor c. capacitor Ans: b d. none of these 123. In a filter circuit is always connected Ans: c in parallel with the load. a. resistor 128.One of the application of zener diode is b. inductor a. Clipper c. capacitor

b. Clamper	c. Clipper
c. Voltage regulator	d. Regulator
d. all above	
	Ans: b
Ans: c	
	134.Series Negative clipper will clip off
129 Clipper circuit are used for	a. positive half cycle of i/p
a rectification	b. both half cycle of i/p
h. Removing part of wave form	c. negative half cycle of i/p
c. Shiftingof DC lovel	d none
d. All	Ansia
Ans: b	
	135. Negative clampers add a DC voltage to the
130.Clamper circuit are used for	AC input
a. rectification	a. Positive
b. Removing part of wave form	b. negative
c. Shifting of DC level	c. zero
d. All	d. both
Ans: c	Ans: b
131. Positive clampers adds DC voltage	136. Series Positive clipper will clip off
to the AC input	a. positive half cycle of i/p
a. Positive	b. both half cycle of i/p
b. negative	 negative half cycle of i/p
c. zero	d. none
d. both	
	Ans: a
Ans: a	
	137. In a series clipper, is connected inn
132 The basic circuit of half wave doubler is	series with load.
a Clamper	a. Diode
h Rectifier	b. inductor
	c. transistor
d Degulator	d capacitor
a. Regulator	
Ans: a	Ans: a
133. The basic circuit of full wave doubler is	138. In aClipper, a diode is connected in
a. Clamper	parallel with the load.
b. Rectifier	a. series

b. combinational	143. In a series clipper, the slope of the transfer
c. parallel	characteristics in transmitting region is
d. two way	a. zero
	b. unity
Ans: c	c. infinite
	d. negative
139. A negative clipper clips offportion of	
the input waveform.	Ans: b
a. positive	
b. negative	144. In a series clipper, the slope of the transfer
c. peak	characteristics in clipping region is
d. none of these	a. zero
	b. unity
Ans: b	c. infinite
	d. negative
140. A positive clipper clips off portion of	
the input waveform.	Ans: a
a. positive	
b. negative	145. In a parallel clipper, Vo = Vin can be
c. peak	obtained in transmitting region by
d, none of these	making
	a. R1>>RL
Ans: a	b. R1=RL
	c. R1< <rl< td=""></rl<>
141. In a series clipper, for a clipping region, the	d. none of these
diode must be incondition.	
a. forward biased	Ans: c
b. reverse biased	
c. none of these	146. In a combinational clipper, when both the
d. a and b	diodes are off, it produces action.
	a. clipping
Ans: b	b. transmitting
	c. exponential
142 In a series clipper for a transmitting	d. none of these
region the diode must be in condition	
a forward biased	Ans: b
h reverse hiased	
c none of these	147. In aclamper, the capacitor gets
d a and h	charged during first quarter of the negative cycle
u. a anu D	of the input.
Ans: 2	a. positive
	b. negative

c. combinational d. two way

Ans: a

148. In aclamper, the capacitor gets charged during first quarter of the positive cycle of the input.

a. positive

- b. negative
- c. combinational
- d. two way

Ans: b

149. Once charged to peak value, a capacitor acts as...... in a clamper.

a. filter

- b. multiplier
- c. battery
- d. rectifier

Ans: c

150. In a clamper, the analysis must start considering that part of the input whicha. reverse biases the diode

b. forward biases the diode

c. discharges the capacitor

d, none of these

Ans: b

151 is assumed in the clamper.

a. capacitor charges exponentially and discharges instantly.

b. capacitor charges instantly and discharges instantly.

c. capacitor charges instantly and does not discharge at all.

d. capacitor charges exponentially and discharges exponentially.

Ans: c

152 is action used in multiplier.

- a. clipping
- b. Clamping
- c. rectifying
- d. slicing

Ans: b

153. In a half wave voltage doubler, the capacitor charges in ------a. alternate half cycleb. each half cyclec. first positive half cycled. none of these

Ans: a

154. The voltage regulation of multipliers isa. very goodb. poorc. zerod. none of theseAns: b

155. ----- is not required in Voltage multipliers

- a. Center tap transformer
- b. Diode
- c. Capacitor
- d. None of these

Ans: a

156. PIV of diode in Full wave doubler is

- a. Vm
- b. 2Vm
- c. 3Vm
- d. none

Ans: b

157. The basic circuit of half wave doubler is a. Clamper

- b. Rectifier
- c. Clipper
- d. Regulator

Ans: a

158. The zener diode is generally operated in

a. Forward breakdown region

b. reverse breakdown region

c. middle breakdown region

d. all above

Ans: b

159. One of the application of zener diode is

- a. Clipper
- b. Clamper
- c. Voltage regulator
- d. all above

Ans: c

160.A zener diode......a. has a high forward-voltage ratingb. has a sharp breakdown at low reverse voltagec. is useful as an amplifier

d. has a negative resistance

Ans: b

161. The doping level in a zener diode is that of a semiconductor diode.

a. more than

b. less than

- c. the same as
- d. none of the above

Ans: a

162.A 12 V zener diode has a 1W power rating.What is the maximum rated zener current?a. 120 mAb. 83.3 mAc. 46.1 mAd. 1A

Ans: b

163.A general purpose diode is more likely to suffer avalanche breakdown rather than zener breakdown because a. its leakage current is small

- b. it has weak covalent bonds
- c. it is lightly doped
- d. it has low reverse resistance

Ans: c

164. Once a zener diode goes into breakdown, its doesn't change mucha. voltageb. currentc. dynamic impedanced. capacitance

Ans: a

165. Load regulation is determined bya. changes in load current and input voltageb. changes in load current and output voltagec. changes in load resistance and input voltaged. changes in zener current and load current

Ans: b

166. For a certain 12 V zener diode, a 10 mA change in zener current produces a 0.1 V change in zener voltage. The Zener impedance for this current range is

a. 1 W	171. For a certain 12 V zener diode, a 10 mA
b. 100 W	change in zener current produces a 0.1 V change
c. 10 W	in zener voltage. The Zener impedance for this
d. 0.1 W	current range is
	a. 1 ohm
Ans: c	b. 100 ohm
167. If the load resistance increases in a zener	c. 10 ohm
regulator, the zener current	d. 0.1 ohm
a. decreases	
b. stays the same	Ans: b
c. increases	
d. equals the source voltage divided by the	172. An optical diode which emits light when
series resistance	forward biased is
	a. LED
Ans: c	b. LCD
	c. TFT
168. Practically zener diodes are operated in	d. None of above
a. Forward breakdown region	
b. reverse breakdown region	Ans: a
c. middle breakdown	
d all above	173. The color of emitted light decided by
	a. Semiconductor material
Ans: h	b. Wavelength
	c. type
169 A zonor diodo bas	d. all above
a one ph-junction	
h two pr-junctions	Ans: a
c three projunctions	
d none of the above	174 The approximate voltage drop across a
u. none of the above	forward- biased LED is
Ansia	a 03V
Alls. d	h 0 7 V
170 A zener diade is exercised in the following	c 5 6 V
mode as a voltage stabilizer	
niode as a voltage stabilizer	0.2.0 V
a. reverse blas	Ans: d
b. forward blas	Alls. d
c. beyond the breakdown region	175 IEDs have replaced incandescent lamps in
a. reverse bias around the knee of breakdown	many applications because they have
region	a a lower operations because they have
	a. a longer life
Ans: a	o, a longer me
	C Idster on-on switching

d. all the advantages as a, b,c,d

Ans: d

176. A display using seven LEDs is called

- a. bar graph display
- b. seven segment display
- c. matrix display
- d. none of these

Ans: b

177. Which of the following group of letters can be displayed on seven segment display?

- a. A,C
- b. b,d
- c. F,C
- d. all of these

Ans: d

178. The internal resistance of a photodiode

a. increases with light intensity when reverse biased

b. decreases with light intensity when reverse biased

c. increases with light intensity when forward biased

d. decreases with light intensity when forward biased

Ans:b

179. To display the digit 0 in a seven segment indicator

- a. C must be off
- b. G must be off
- c. F must be on
- d. all segments must be lighted

Ans: b

180. As compared to a silicon rectifier diode, an LED has a

a. lower forward voltage and lower breakdown voltage

b. lower forward voltage and higher breakdown voltage

c. higher forward voltage and lower breakdown voltage

d. higher forward voltage and higher breakdown voltage

Ans: c

181. Types of seven segment display are

- a. Common anode type
- b. common gate type
- c. common cathode type
- d. both A and B

Ans: d

182. An infrared LED is optically coupled to a photodiode. When the LED is turned off, the reading on an ammeter in series with the reverse biased photodiode will

- a. not change
- b. decrease
- c. increase
- d. fluctuate

Ans: b

- 183. The semiconductor material used for LED is
- a. Gallium Arsenide
- b. gallium bromide
- c. Silicon
- d. Germanium

Ans: a

184. The graph of _____ is called spectral response of LED.

a. Forward Voltage Vs wavelength	b. forward biased
b. Current Vs forward voltage	c. parallel with load
c. current Vs forward voltage	d. none of these
d. light output Vs wavelength	
	Ans: a
Ans: d	
	190 is always operated in reverse
185. The LED emits light when biased.	biased condition.
a. reverse	a. LED
b. unbiased	b. Photodiode
c. forward	c. Transistor
d. none of these	d. Rectifier
Ans: d	Ans: b
186 The LED works on the principle of	191 The current in photodiode increases as the
a. flurescense	light intensity
a. Indioscence	a, remains same
	b. decreases
d none of these	c. increases
u. none of these	d. none of these
Ans: c	
7 (15. C	Ans: c
187 GaAsP LEDs are used to produce	
color light.	192. The dark current in photodiode is due to
a red	charge carriers.
b. green	a. majority
c. orange	b. minority
d. white	c. both the
	d. none of these
Ans: a	
	Ans: b
188. Thecontrols the brightness of LED.	193. The photodiode isdevice.
a. Forward voltage	a. photoemitter
b. Forward current	b. photorejector
c. Materal used	c. photodetector
d. none of these	d. none of these
Ans: b	Ans: d
189. A photodiode operates in condition.	194. The luminous efficiency of LEDs is
a. reverse biased	a. high

b. low c. zero	b. reverse currentc. intensity of light
d. none of these	d. none of these
Ans: b	Ans: c
195. The luminous efficiency of LEDs is	200. The intensity of light is measured in
a lumens/watt	 a. lm/A
h watts/lumen	h Im/W
c_lumens/degree C	c. 1m/w2
d. lumens/ampere	d. Lm/m2
Ans: a	Ans: d
196is used in optocouplers.	201. The photodiode characteristics lies in
a. Zener	quadrant.
b. LED	a. first
c. SCR	b. second
d. Transformer	c. third
	d. fourth
Ans: b	
	Ans: c
197. The photodiode current under no light is	
calledcurrent.	202. The current is photodiode is due to
a. forward	carriers.
b. maximum	a. majority
c. dark	b. minority
a. none of these	c. both
Ancia	a. none of these
	Ans: h
198 The dark current of photodiode is always	203 The LED is device
a large	a photoemitter
b verv small	h photorejector
c. zero	c. photodetector
d. infinite	d. none of these
Ans: b	Ans: a
199. Photo current is directly proportional to	204. A photodiode converts
a. forward current	a. light energy into chemical energy

- b. chemical energy into electrical energy
- c. light energy into electrical energy
- d. electrical energy into light energy

Ans: c

205. A LED converts____.

- a. light energy into chemical energy
- b. chemical energy into electrical energy
- c. light energy into electrical energy
- d. electrical energy into light energy

Ans: d